



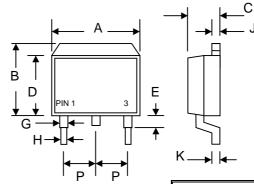
## 8.0A HIGH VOLTAGE SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

# **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for **Transient Protection**
- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity **Protection Applications**

## **Mechanical Data**

- Case: D<sup>2</sup>PAK/TO-263, Molded Plastic •
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 1.7 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- Lead Free: For RoHS / Lead Free Version, Add "-LF" Suffix to Part Number, See Page 4



Case

D <sup>2</sup> PAK/TO-263			
Dim	Min	Max	
Α	9.80	10.40	
В	9.60	10.60	
С	4.40	4.80	
D	8.50	9.10	
E	2.80		
G	1.00	1.40	
н	—	0.90	
J	1.20	1.40	
К	0.30	0.70	
Р	2.35	2.75	
All Dimensions in mm			

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# Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

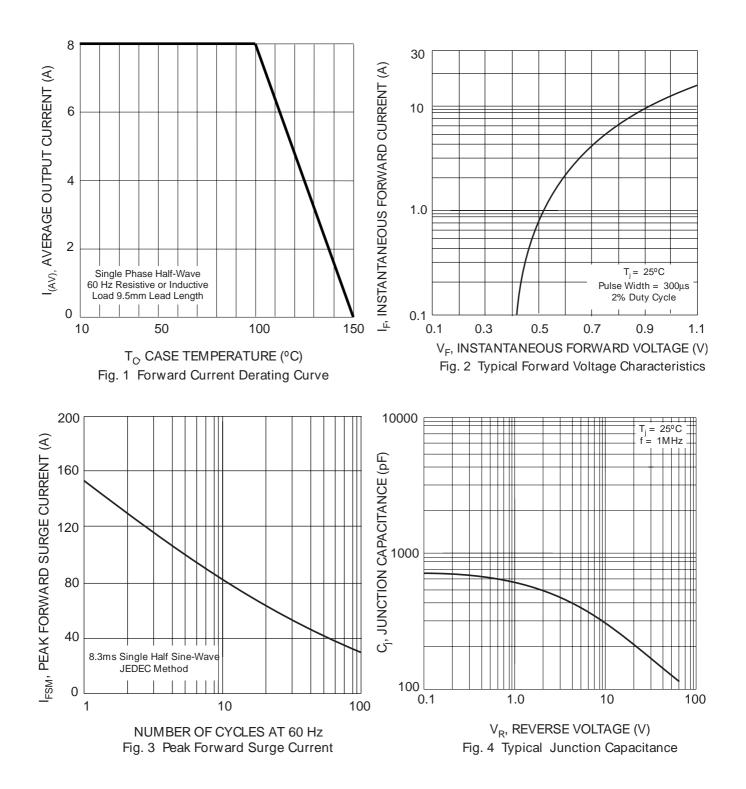
Characteristic	Symbol	SB8150D	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	150	V
RMS Reverse Voltage	Vr(rms)	105	V
Average Rectified Output Current $@T_c = 100^{\circ}C$	ю	8.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	150	A
Forward Voltage $@I_F = 8.0A$	Vfm	0.92	V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	Irm	0.5 50	mA
Typical Junction Capacitance (Note 1)	Cj	400	pF
Typical Thermal Resistance (Note 2)	R	3.0	°C/W
Operating and Storage Temperature Range	Тј, Тѕтс	-65 to +150	°C

PIN1+ O

PIN 3 - O-

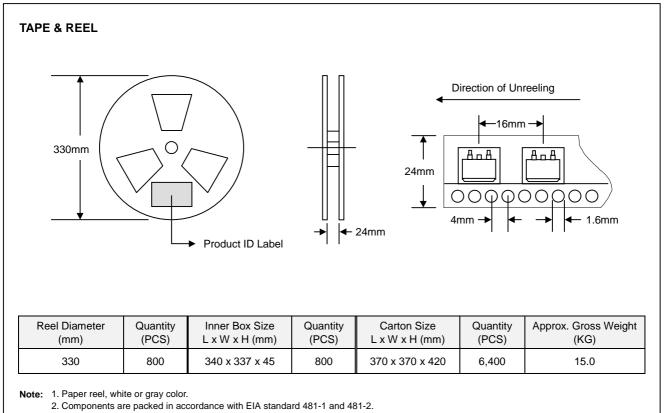
Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance junction to case mounted on heatsink.



#### MARKING INFORMATION **RECOMMENDED FOOTPRINT** 0.33 (8.38) € 0.12 (3.05) WTE SB8150D ▲ 0.08 (2.032) 0.42 0.24 V (10.66) **★** 0.04 (6.096) (1.016) WTE = Manufacturer's Logo SB8150D = Device Number 0.63 (17.02) Polarity = As Marked on Body inches(mm)

# PACKAGING INFORMATION



## **ORDERING INFORMATION**

Product No.	Package Type	Shipping Quantity
SB8150D-T3	D <sup>2</sup> PAK	800/Tape & Reel

1. Shipping quantity given is for minimum packing quantity only. For minimum

order quantity, please consult the Sales Department. To order RoHS / Lead Free version (with Lead Free finish), add "-LF" suffix to part number above. For example, SB8150D-T3-LF. 2.

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